TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSIV)

2SK3700

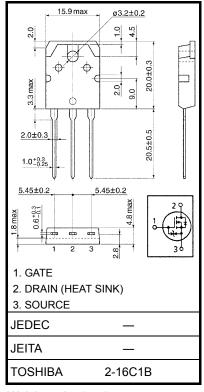
Switching Regulator Applications

Unit: mm

- Low drain-source ON-resistance: $R_{DS (ON)} = 2.0 \Omega (typ.)$
- High forward transfer admittance: |Y_{fs}| = 4.5 S (typ.)
- Low leakage current: $I_{DSS} = 100 \mu A \text{ (max) (V}_{DS} = 720 \text{ V)}$
- Enhancement model: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit | |
|--|----------------|------------------|-----------|------|--|
| Drain-source voltage | | V_{DSS} | 900 | V | |
| Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) | | V_{DGR} | 900 | V | |
| Gate-source voltage | | V_{GSS} | ±30 | ٧ | |
| Drain current | DC (Note 1) | I _D | 5 | Α | |
| | Pulse (Note 1) | I _{DP} | 15 | _ ^ | |
| Drain power dissipation (Tc=25°C) | | P_{D} | 150 | W | |
| Single pulse avalanche energy (Note 2) | | E _{AS} | 351 | mJ | |
| Avalanche current | | I _{AR} | 5 | Α | |
| Repetitive avalanche e | nergy (Note 3) | E _{AR} | 15 | mJ | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature ra | ange | T _{stg} | -55 to150 | °C | |



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|-------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 0.833 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 50 | °C/W |

Note 1: Ensure that the temperature does not exceed 150 $^{\circ}$ C.

Note 2: $V_{DD} = 90 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 25.7 mH, $R_G = 25 \ \Omega$, $I_{AR} = 5 \ A$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

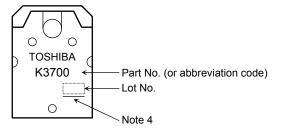
Electrical Characteristics (Ta = 25°C)

| Chara | acteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|---------------------------------------|----------------------|---|-----|------|-----|------|
| Gate leakage cur | rent | I _{GSS} | $V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±10 | μА |
| Gate-source brea | akdown voltage | V (BR) GSS | $I_{G} = \pm 10 \mu$ A, $V_{DS} = 0V$ | ±30 | _ | _ | V |
| Drain cut-OFF cu | | | V _{DS} = 720 V, V _{GS} = 0 V | | _ | 100 | μА |
| Drain-source bre | Drain-source breakdown voltage V (BR) | | I _G = 10mA, V _{GS} = 0 V | 900 | _ | | V |
| Gate threshold vo | oltage | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 2.0 | _ | 4.0 | V |
| Drain-source ON | resistance | R _{DS} (ON) | V _{GS} = 10 V, I _D = 3 A | | 2.0 | 2.5 | Ω |
| Forward transfer | admittance | Y _{fs} | V _{DS} = 20 V, I _D = 3 A | 2.0 | 4.5 | | S |
| Input capacitance | | C _{iss} | V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz | | 1150 | | pF |
| Reverse transfer capacitance | | C _{rss} | | | 20 | | |
| Output capacitance | | Coss | | | 100 | | |
| Switching time | Rise time | t _r | V_{GS} V_{GS} V_{GS} V_{DD} V_{DD} V_{DD} V_{DD} V_{DD} | _ | 30 | _ | |
| | Turn-ON time | t _{on} | | _ | 70 | _ | no |
| | Fall time | t _f | | _ | 60 | _ | ns |
| | Turn-OFF time | t _{off} | | _ | 170 | _ | |
| Total gate charge (gate-source plus gate-drain) | | Qg | | _ | 28 | _ | nC |
| Gate-source charge | | Q _{gs} | $V_{DD} = 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 5 \text{ A}$ | | 17 | | |
| Gate-drain ("miller") charge | | Q _{gd} | | _ | 11 | _ | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|---|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | _ | _ | _ | 5 | Α |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 15 | Α |
| Forward voltage (diode) | V _{DSF} | I _{DR} = 5 A, V _{GS} = 0 V | _ | _ | -1.7 | V |
| Reverse recovery time | t _{rr} | $I_{DR} = 5 \text{ A}, V_{GS} = 0 \text{ V},$ | _ | 900 | _ | ns |
| Reverse recovery charge | Qrr | dI _{DR} /dt = 100 A/μs | _ | 5.4 | _ | μC |

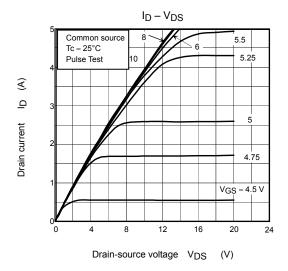
Marking

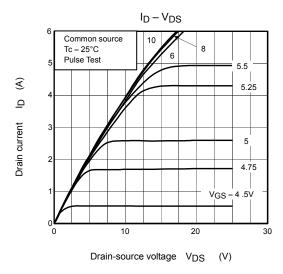


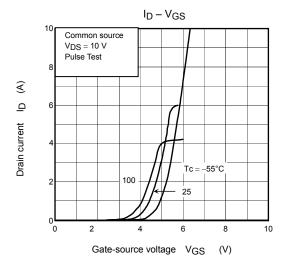
Note 4: A line under a Lot No. identifies the indication of product Labels.

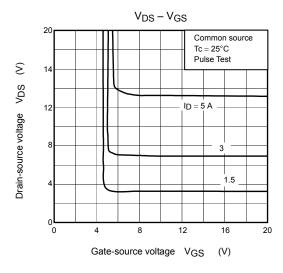
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

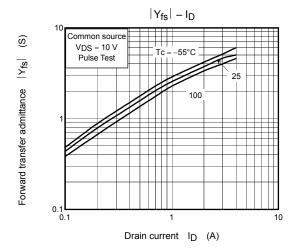
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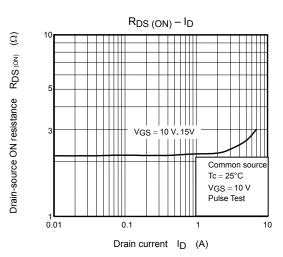




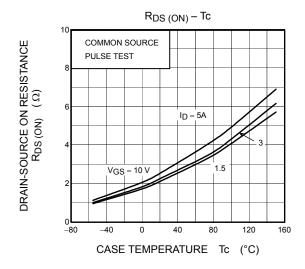


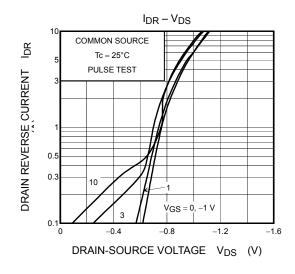


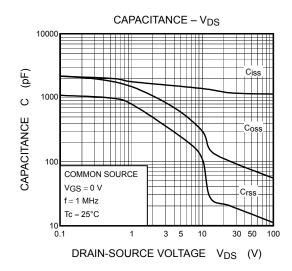


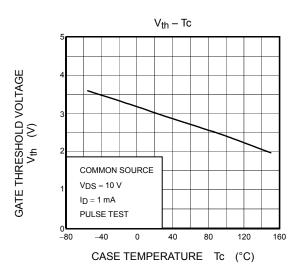


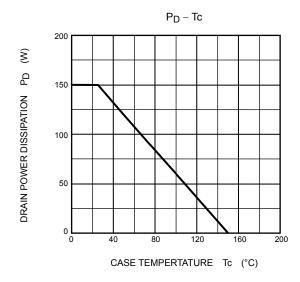
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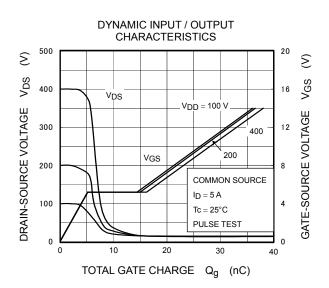


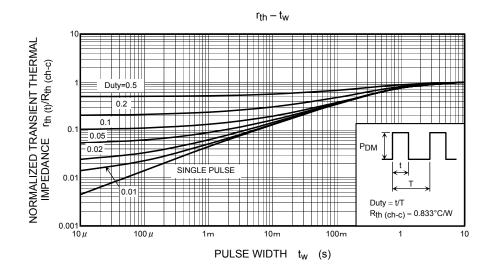


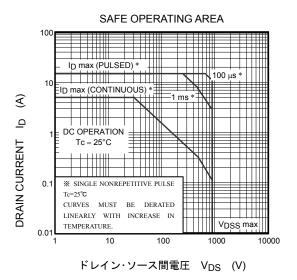


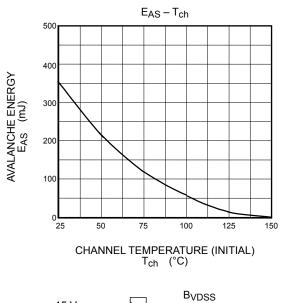


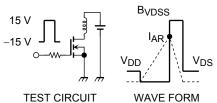












$$R_G = 25 \Omega$$

$$V_{DD} = 90 \text{ V, L} = 25.7 \text{mH}$$

$$E_{AS} = \frac{1}{2} \cdot \text{L} \cdot \text{I}^2 \cdot \left(\frac{\text{BVDSS}}{\text{BVDSS} - \text{VDD}}\right)$$

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